



Power Supply Characteristics

Parameter	Description	Test Conditions	Typ. ^[6]	Max.	Unit
I_{CC}	Quiescent Power Supply Current	$V_{CC} = \text{Max.}, V_{IN} \leq 0.2V,$ $V_{IN} \geq V_{CC} - 0.2V$	0.1	0.2	mA
ΔI_{CC}	Quiescent Power Supply Current (TTL inputs HIGH)	$V_{CC} = \text{Max.}, V_{IN} = 3.4V^{[9]}$ $f_I = 0, \text{Outputs Open}$	0.5	2.0	mA
I_{CCD}	Dynamic Power Supply Current ^[10]	$V_{CC} = \text{Max.}, \text{One Bit Toggling, Preset Mode, 50\% Duty Cycle, Outputs Open,}$ $\overline{MR} = V_{CC} = \overline{SR},$ $\overline{PL} = \overline{CE} = \overline{U/D} = \overline{CP} = \text{GND},$ $V_{IN} \leq 0.2V \text{ or } V_{IN} \geq V_{CC} - 0.2V$	0.06	0.12	mA/MHz
I_C	Total Power Supply Current ^[11]	$V_{CC} = \text{Max.}, \text{Preset Mode, 50\% Duty Cycle, Outputs Open, One Bit Toggling at } f_I = 5 \text{ MHz,}$ $\overline{PL} = \overline{CE} = \overline{U/D} = \overline{CP} = \text{GND},$ $V_{IN} = V_{CC}, V_{IN} = \text{GND}$	0.4	0.8	mA
		$V_{CC} = \text{Max.}, \text{Preset Mode, 50\% Duty Cycle, Outputs Open, One Bit Toggling at } f_I = 5 \text{ MHz,}$ $V_{IN} = 3.4V \text{ or } V_{IN} = \text{GND}$	0.7	1.8	mA
		$V_{CC} = \text{Max.}, \text{Preset Mode, 50\% Duty Cycle, Outputs Open, Four Bits Toggling at } f_I = 5 \text{ MHz,}$ $\overline{PL} = \overline{CE} = \overline{U/D} = \overline{CP} = \text{GND},$ $V_{IN} = V_{CC}, V_{IN} = \text{GND}$	1.3	2.6 ^[12]	mA
		$V_{CC} = \text{Max.}, \text{Preset Mode, 50\% Duty Cycle, Outputs Open, Four Bits Toggling at } f_I = 5 \text{ MHz,}$ $\overline{PL} = \overline{CE} = \overline{U/D} = \overline{CP} = \text{GND},$ $V_{IN} = 3.4V \text{ or } V_{IN} = \text{GND}$	2.3	6.6 ^[12]	mA

Notes:

9. Per TTL driven input ($V_{IN} = 3.4V$); all other inputs at V_{CC} or GND.

10. This parameter is not directly testable, but is derived for use in total Power Supply calculations.

- 11. $I_C = I_{\text{QUIESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$
- $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD}(f_0/2 + f_I N_I)$
- I_{CC} = Quiescent Current with CMOS input levels
- ΔI_{CC} = Power Supply Current for a TTL HIGH input ($V_{IN} = 3.4V$)
- D_H = Duty Cycle for TTL inputs HIGH

- N_T = Number of TTL inputs at D_H
- I_{CCD} = Dynamic Current caused by an input transition pair (HLH or LHL)
- f_0 = Clock frequency for registered devices, otherwise zero
- f_I = Input signal frequency
- N_I = Number of inputs changing at f_I

All currents are in milliamps and all frequencies are in megahertz.
12. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.